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**CNW11AV-1**

**CNW11AV-2**

**CNW11AV-3**

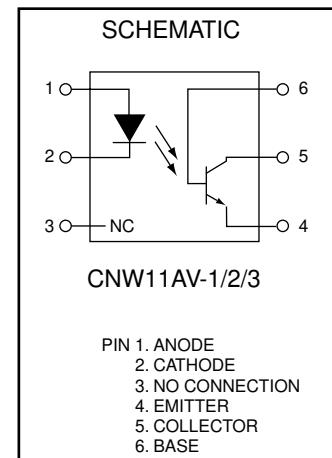
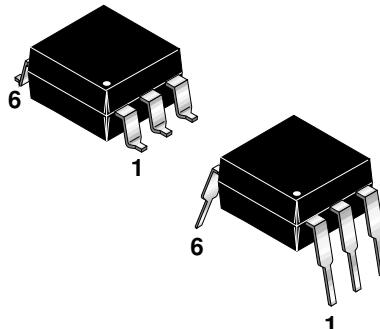
## DESCRIPTION

The CNW11AV series are high voltage optocouplers in a wide body dual-in-line package (DIP).

Each optocoupler consists of a GaAs infrared emitter optically coupled to a silicon npn phototransistor with the base connected.

## FEATURES

- Minimum 2 mm isolation thickness between emitter and receiver
- A wide body encapsulation with a pin distance of 10.16 mm
- An external clearance of 9.6 mm minimum and an external creepage of 10 mm minimum
- High current transfer ratio and low saturation voltage, making the device suitable for use with TTL integrated circuits
- High degree of AC and DC insulation (4000 V (RMS) and 5656 V (DC))
- Collector-emitter breakdown Voltage: 70 V
- Low isolation capacitance of 0.5 pF maximum
- UL recognized (File # E90700)
- VDE recognized (File # 76876)
  - Ordering option '300' (e.g. CNW11AV-1.300)



## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Units
<b>TOTAL DEVICE</b>			
Storage Temperature Range	$T_{STG}$	-55 to 150	°C
Ambient Operating Temperature Range	$T_{OPR}$	-40 to 100	°C
Lead Soldering Temperature	$T_{SOL}$	260 for 10 sec	°C
Junction Temperature	$T_J$	125	°C
<b>EMITTER</b>			
Forward Current - Continuous	$I_F$	100	mA
Forward Current - Peak ( $t_{on} = 10\mu s$ , $\delta = 0.01$ )	$I_F(pk)$	3	A
Reverse Voltage	$V_R$	6	V
Total Power Dissipation @ $T_A = 25^\circ C$	$P_D$	200	mW
Derate Linearly From $25^\circ C$		2.0	mW/°C
<b>DETECTOR</b>			
Collector Current-Continuous	$I_C$	100	mA
Emitter-Collector Voltage	$V_{ECO}$	7	V
Collector-Emitter Voltage	$V_{CEO}$	70	V
Collector-Base Voltage	$V_{CBO}$	70	V
Total Power Dissipation @ $T_A = 25^\circ C$	$P_D$	200	mW
Derate Linearly From $25^\circ C$		2.0	mW/°C

**CNW11AV-1    CNW11AV-2    CNW11AV-3**

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ C$  Unless otherwise specified)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
<b>EMITTER</b>	$I_F = 10 \text{ mA}$	$V_F$	0.8	1.15	1.50	V
	$I_F = 10 \text{ mA}, T_A = -55^\circ C$		0.9	—	1.70	
	$I_F = 10 \text{ mA}, T_A = 100^\circ C$		0.7	—	1.40	
Reverse Leakage Current	$V_R = 6.0 \text{ V}$	$I_R$	—	—	10	$\mu\text{A}$
Input Capacitance	$V_I = 0, f = 1 \text{ MHz}$	$C_J$	—	25	100	$\text{pF}$
<b>DETECTOR</b>	$I_C = 1.0 \text{ mA}$	$BV_{CEO}$	70	—	—	V
	$I_C = 0.1 \text{ mA}$	$BV_{CBO}$	70	—	—	V
	$I_E = 0.1 \text{ mA}$	$BV_{ECO}$	7	—	—	V
	$I_E = 0.1 \text{ mA}$	$BV_{EBO}$	7	—	—	V
	$V_{CE} = 10 \text{ V}, I_F = 0, T_A = 25^\circ C$	$I_{CEO}$	—	0.5	50	nA
	$V_{CE} = 10 \text{ V}, I_F = 0, T_A = 70^\circ C$		—	—	10	$\mu\text{A}$
	$I_F = 0, V_{CB} = 10 \text{ V}$	$I_{CBO}$	—	—	20	nA

**ISOLATION CHARACTERISTICS**

Characteristic	Test Conditions	Symbol	Min	Typ	Max	Units
Input-Output Isolation Voltage	DC Value, Time = 1 min.	$V_{ISO}$	5,656	—	—	V
	RMS Value, Time = 1 min.		4,000	—	—	
Isolation Resistance	$V_{I-O} = \pm 500 \text{ VDC}$	$R_{ISO}$	1	10	—	$\text{T}\Omega$
Isolation Capacitance	$V = 0\text{V}, f = 1 \text{ MHz}$	$C_{ISO}$	—	0.3	0.5	pF
Output Capacitance	$V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	$C_O$	—	4.5	—	pF

**TRANSFER CHARACTERISTICS** ( $T_A = 25^\circ C$  Unless otherwise specified.)

DC Characteristics	Test Conditions	Symbol	Device	Min	Typ	Max	Units
Output/Input Current Transfer Ratio	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	CTR	CNW11AV-1	100	—	300	%
			CNW11AV-2	50	—	—	
			CNW11AV-3	20	—	—	
Collector-Emitter Saturation Voltage	$I_F = 20 \text{ mA}, I_C = 2 \text{ mA}$	$V_{CE(SAT)}$	All	—	0.1	0.4	V
Common Mode Rejection Ratio	$I_C = 2 \text{ mA}, V_{CC} = 5 \text{ V}, f = 10 \text{ kHz}, R_L = 1 \text{ k}\Omega$	CMRR	All	—	-60	—	dB
AC Characteristics	Test Conditions	Symbol	Device	Min	Typ	Max	Units
Saturated Switching Times	$I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega$	$t_{on}$	All	—	3	15	$\mu\text{s}$
		$t_{off}$	All	—	2.5	15	$\mu\text{s}$

**CNW11AV-1**

**CNW11AV-2**

**CNW11AV-3**

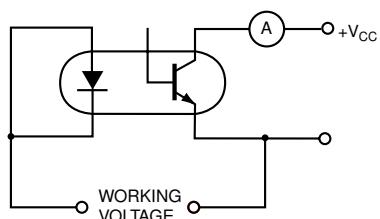


Fig. 1 Test Circuit

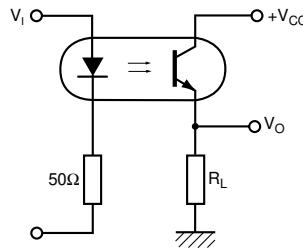


Fig. 2 Switching Circuit

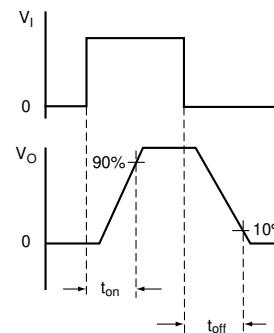


Fig. 3 Waveforms

Fig. 4 LED Forward Voltage vs. Forward Current

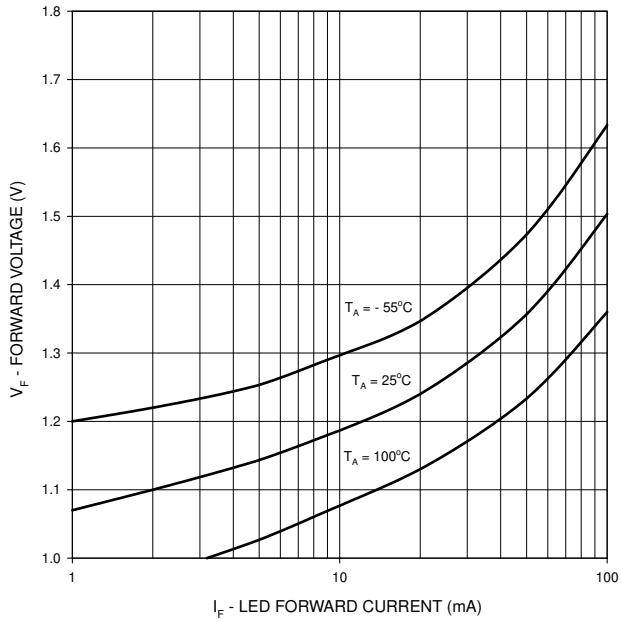


Fig. 5 Normalized CTR vs. Forward Current

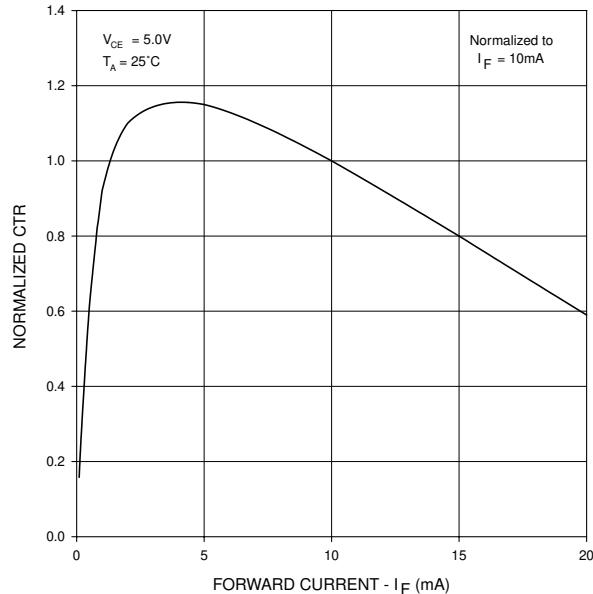


Fig. 6 Normalized CTR vs. Temperature

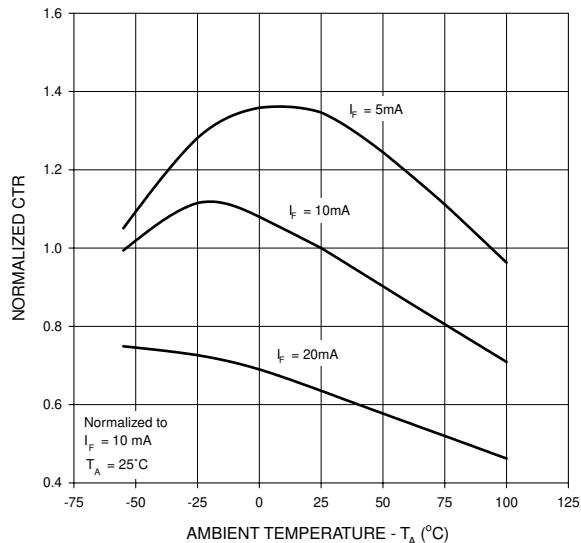
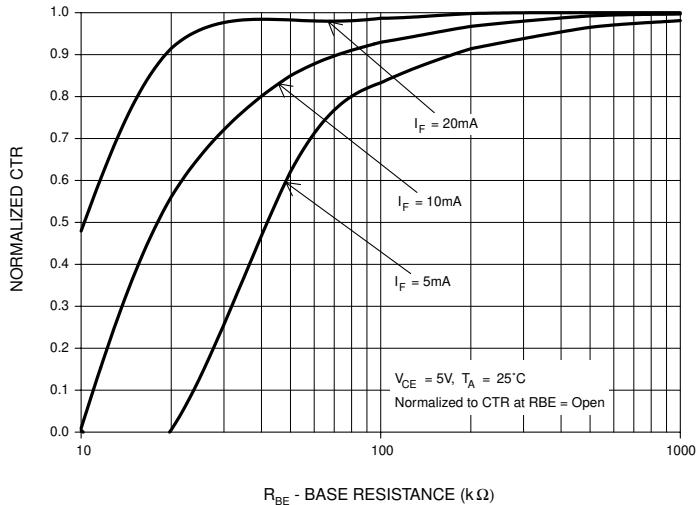
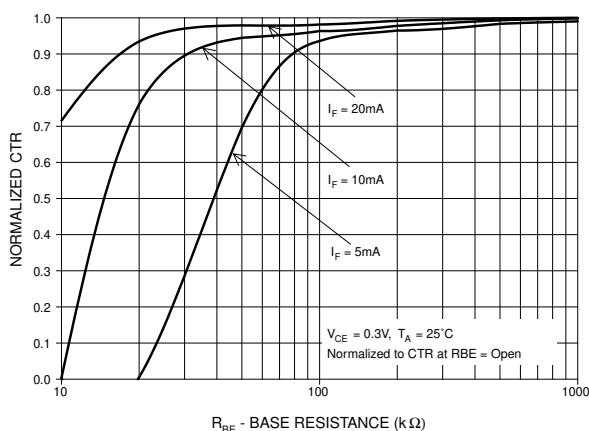


Fig. 7 CTR vs. R<sub>BE</sub> (Unsaturated)

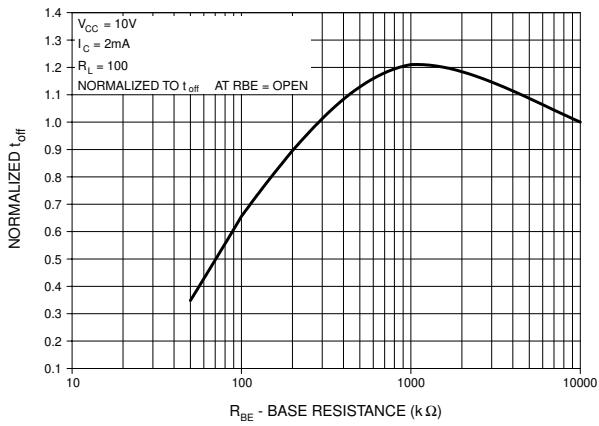


**CNW11AV-1    CNW11AV-2    CNW11AV-3**

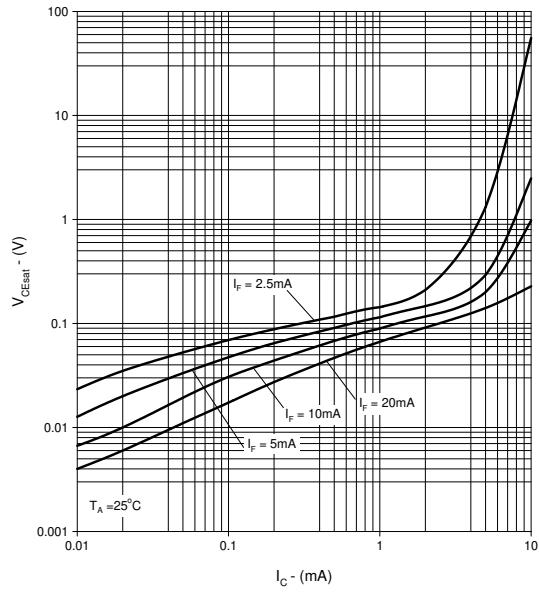
**Fig. 8 CTR vs. R<sub>BE</sub> (Saturated)**



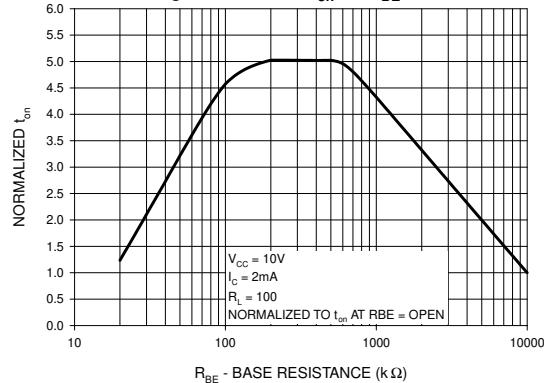
**Fig. 10 Normalized t<sub>off</sub> vs. R<sub>BE</sub>**



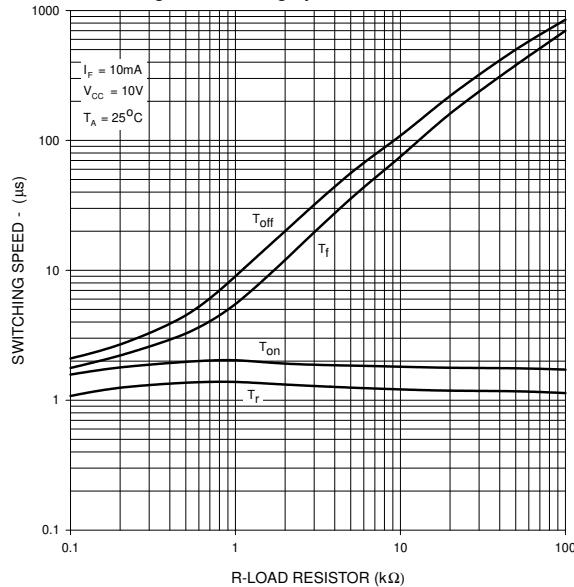
**Fig. 12 Collector-Emitter Saturation Voltage vs Collector Current**



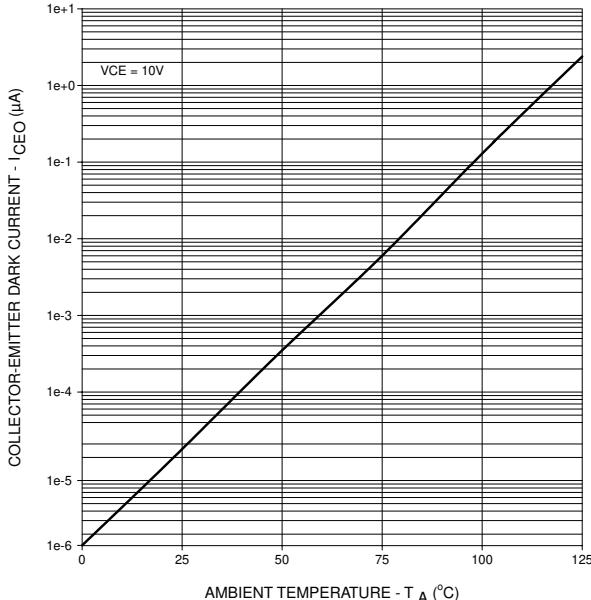
**Fig. 9 Normalized t<sub>on</sub> vs. R<sub>BE</sub>**



**Fig. 11 Switching Speed vs. Load Resistor**

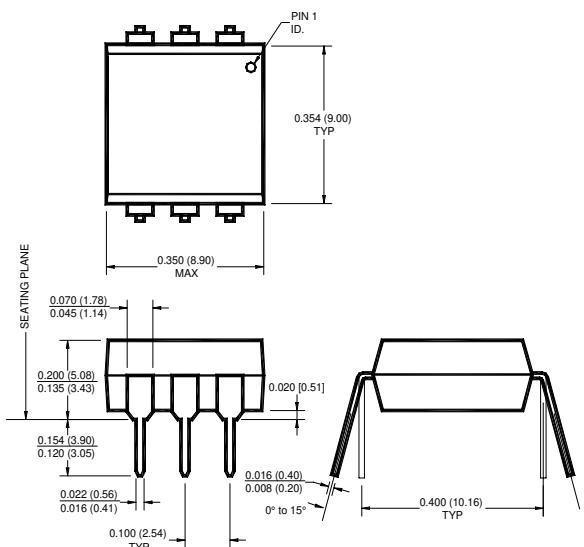


**Fig. 13 Dark Current vs. Ambient Temperature**

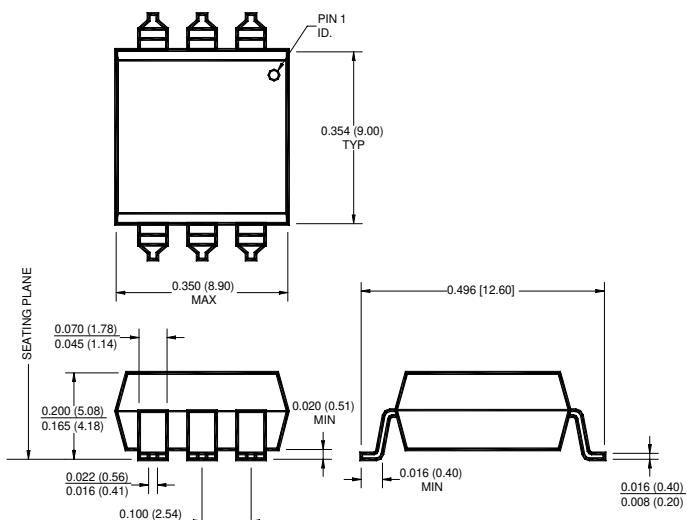


**CNW11AV-1    CNW11AV-2    CNW11AV-3**

**Package Dimensions (Through Hole)**



**Package Dimensions (Surface Mount)**



**NOTE**

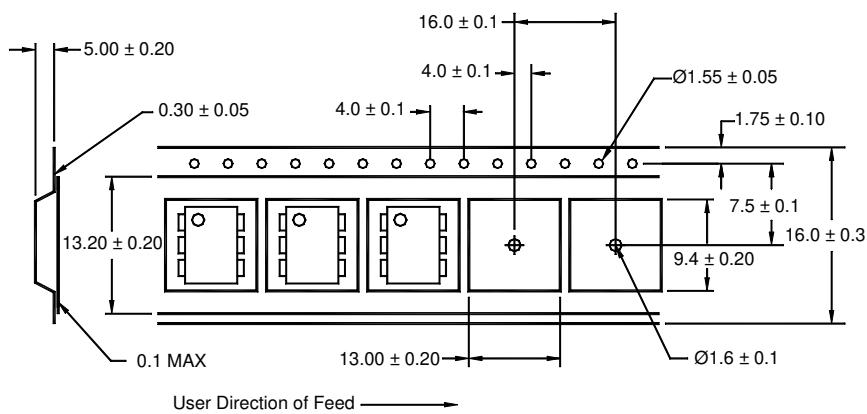
All dimensions are in inches (millimeters)

**CNW11AV-1    CNW11AV-2    CNW11AV-3**

**ORDERING INFORMATION**

Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and reel
300	.300	VDE 0884

**Carrier Tape Specifications ("D" Taping Orientation)**



**NOTE**

All dimensions are in inches (millimeters)

**CNW11AV-1    CNW11AV-2    CNW11AV-3****DISCLAIMER**

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